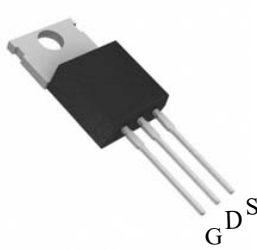


N-Channel 80 V (D-S) MOSFET

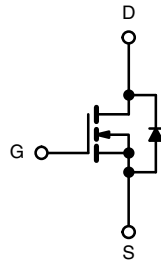
PRODUCT SUMMARY

V _{DS} (V)	R _{DS(on)} (Ω) Max.	I _D (A)	Q _g (Typ.)
80	0.0048 at V _{GS} = 10 V	120 ^a	161 nC

TO-220 Pin Configuration



Top View



N-Channel MOSFET

FEATURES

- DT-Trench Power MOSFET
- 100 % R_g and UIS Tested



RoHS
COMPLIANT

APPLICATIONS

- Primary Side Switching
- Synchronous Rectification
- DC/AC Inverters
- LED Backlighting

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS}	80	V	
Gate-Source Voltage	V _{GS}	± 20		
Continuous Drain Current (T _J = 150 °C)	I _D	T _C = 25 °C	120 ^a	A
		T _C = 70 °C	92	
		T _A = 25 °C	35 ^b	
		T _A = 70 °C	21 ^b	
Pulsed Drain Current (t = 100 μs)	I _{DM}	460		
Continuous Source-Drain Diode Current	I _S	T _C = 25 °C	120 ^a	
		T _A = 25 °C	15 ^b	
Single Pulse Avalanche Current	I _{AS}	110		
Single Pulse Avalanche Energy	E _{AS}	1450	mJ	
Maximum Power Dissipation	P _D	T _C = 25 °C	255	W
		T _C = 70 °C	160	
		T _A = 25 °C	5 ^b	
		T _A = 70 °C	3.3 ^b	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	- 55 to 150	°C	
Soldering Recommendations (Peak Temperature)		260		

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^{b, f}	R _{thJA}	10	16	°C/W
Maximum Junction-to-Case (Drain)	R _{thJC}	0.50	0.68	

Notes

- Package limited.
- Surface mounted on 1" x 1" FR4 board.

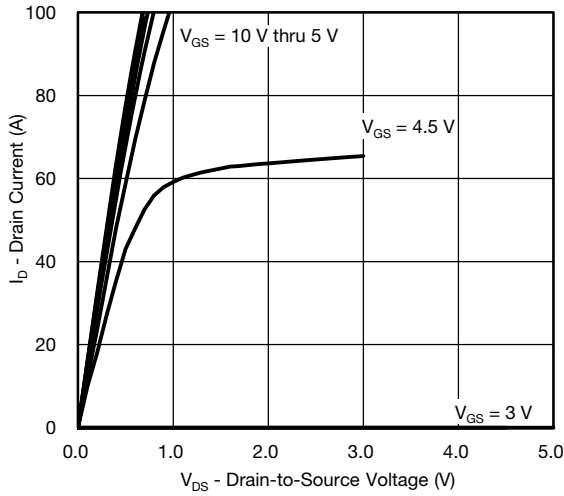
SPECIFICATIONS ($T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted)							
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0\text{ V}, I_D = 250\text{ }\mu\text{A}$	80			V	
V_{DS} Temperature Coefficient	$\Delta V_{DS}/T_J$	$I_D = 250\text{ }\mu\text{A}$		37		mV/°C	
$V_{GS(th)}$ Temperature Coefficient	$\Delta V_{GS(th)}/T_J$			-6			
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\text{ }\mu\text{A}$	1.5		3.5	V	
Gate-Source Leakage	I_{GSS}	$V_{DS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$			± 100	nA	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 64\text{ V}, V_{GS} = 0\text{ V}$			1	μA	
		$V_{DS} = 64\text{ V}, V_{GS} = 0\text{ V}, T_J = 55\text{ }^\circ\text{C}$			10		
On-State Drain Current ^a	$I_{D(on)}$	$V_{DS} \geq 5\text{ V}, V_{GS} = 10\text{ V}$	460			A	
Drain-Source On-State Resistance ^a	$R_{DS(on)}$	$V_{GS} = 10\text{ V}, I_D = 40\text{ A}$		0.0048	0.006	Ω	
Forward Transconductance ^a	g_{fs}	$V_{DS} = 25\text{ V}, I_D = 20\text{ A}$		90		S	
Dynamic^b							
Input Capacitance	C_{iss}	$V_{DS} = 64\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$		6255		pF	
Output Capacitance	C_{oss}			550			
Reverse Transfer Capacitance	C_{rss}			366			
Total Gate Charge	Q_g	$V_{DS} = 64\text{ V}, V_{GS} = 10\text{ V}, I_D = 40\text{ A}$		161		nC	
		$V_{DS} = 64\text{ V}, V_{GS} = 6\text{ V}, I_D = 30\text{ A}$		95			
Gate-Source Charge	Q_{gs}	$V_{DS} = 64\text{ V}, V_{GS} = 4.5\text{ V}, I_D = 20\text{ A}$		80			
Gate-Drain Charge	Q_{gd}			33			
Output Charge	Q_{oss}			12			
Gate Resistance	R_g	$V_{DS} = 50\text{ V}, V_{GS} = 0\text{ V}$ $f = 1\text{ MHz}$		61			Ω
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 40\text{ V}, R_L = 4\text{ }\Omega$ $I_D \cong 10\text{ A}, V_{GEN} = 10\text{ V}, R_g = 1\text{ }\Omega$		1.5		ns	
Rise Time	t_r			24			
Turn-Off Delay Time	$t_{d(off)}$			20			
Fall Time	t_f			83			
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 40\text{ V}, R_L = 4\text{ }\Omega$ $I_D \cong 10\text{ A}, V_{GEN} = 6.0\text{ V}, R_g = 1\text{ }\Omega$		25			
Rise Time	t_r			73			
Turn-Off Delay Time	$t_{d(off)}$			34			
Fall Time	t_f			28			
Drain-Source Body Diode Characteristics							
Continuous Source-Drain Diode Current	I_S	$T_C = 25\text{ }^\circ\text{C}$			120		A
Pulse Diode Forward Current ($t = 100\text{ }\mu\text{s}$)	I_{SM}				460		
Body Diode Voltage	V_{SD}	$I_S = 5\text{ A}$		0.7	1.2		V
Body Diode Reverse Recovery Time	t_{rr}	$I_F = 10\text{ A}, di/dt = 100\text{ A}/\mu\text{s}, T_J = 25\text{ }^\circ\text{C}$		39		ns	
Body Diode Reverse Recovery Charge	Q_{rr}			32		nC	
Reverse Recovery Fall Time	t_a			20		ns	
Reverse Recovery Rise Time	t_b			19			

Notes

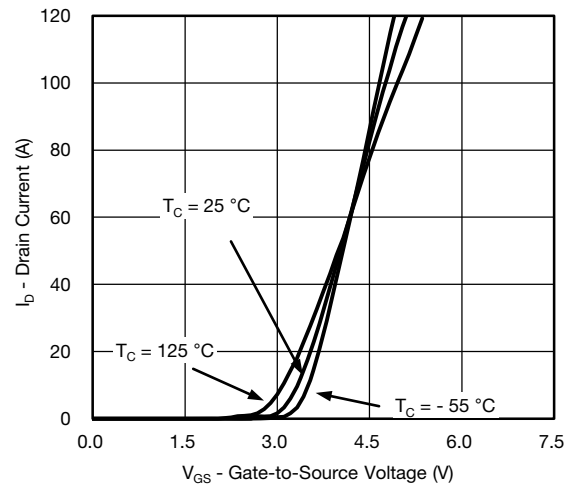
- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
 b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

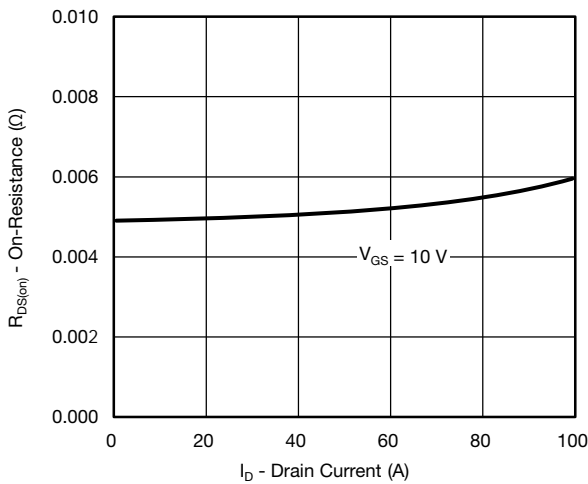
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



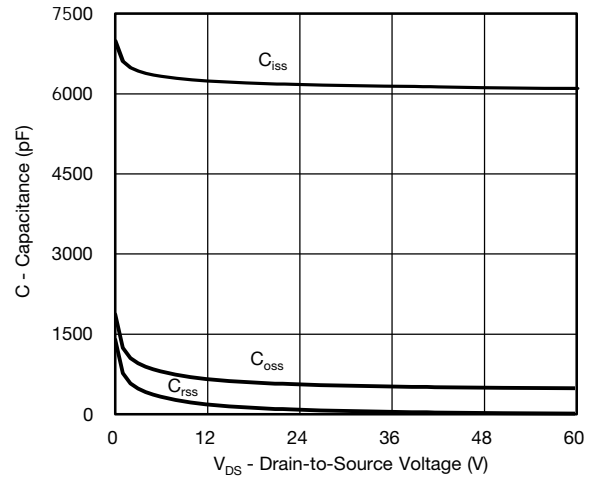
Output Characteristics



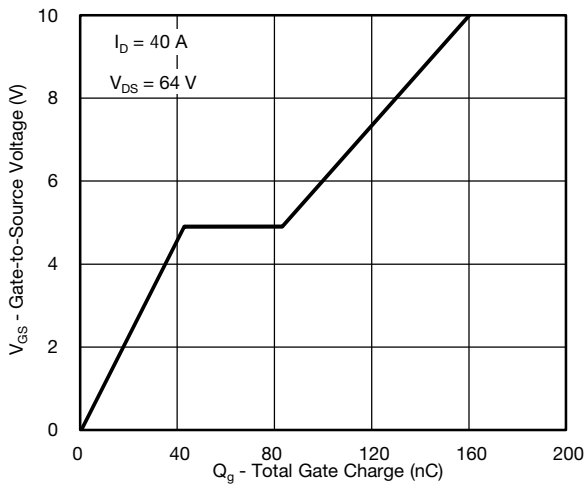
Transfer Characteristics



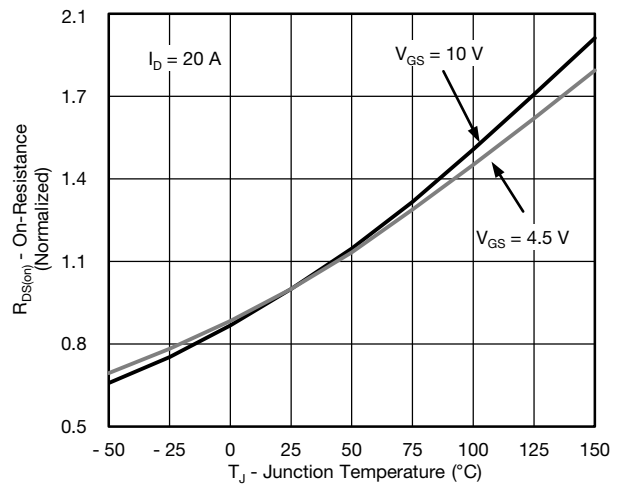
On-Resistance vs. Drain Current



Capacitance

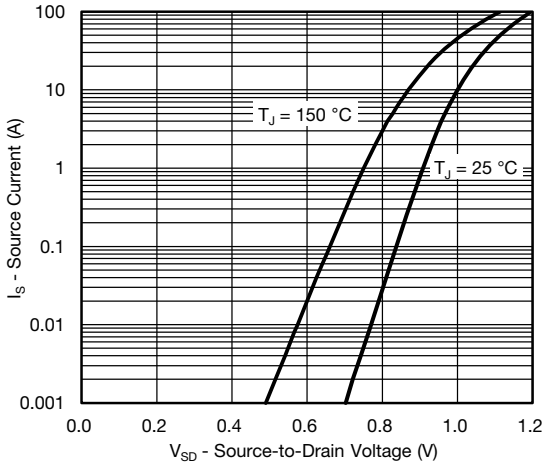


Gate Charge



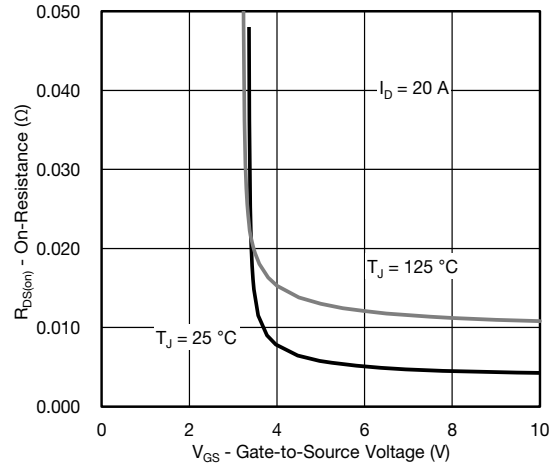
On-Resistance vs. Junction Temperature

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

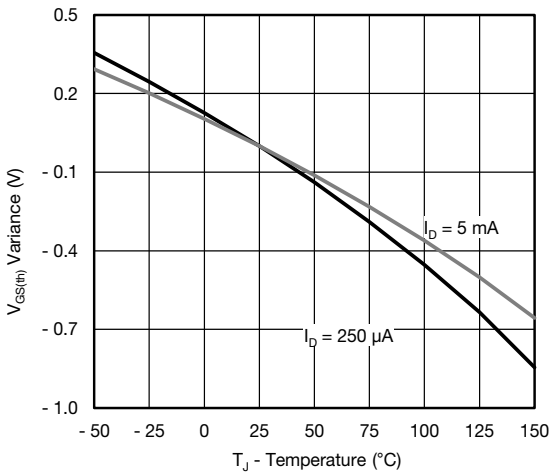


Source-Drain Diode Forward Voltage

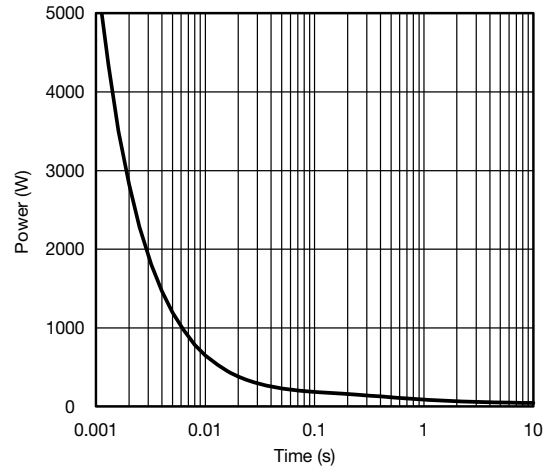
3



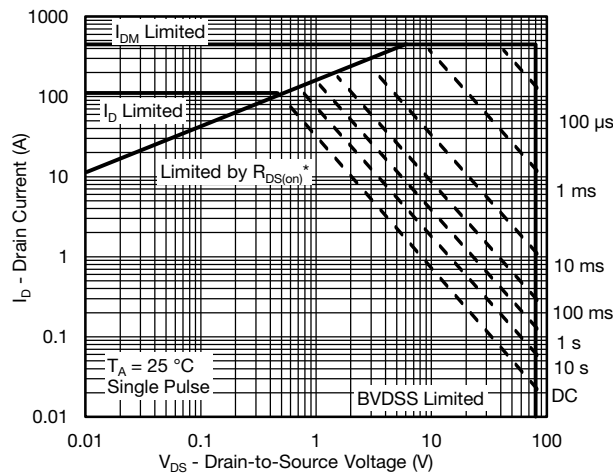
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



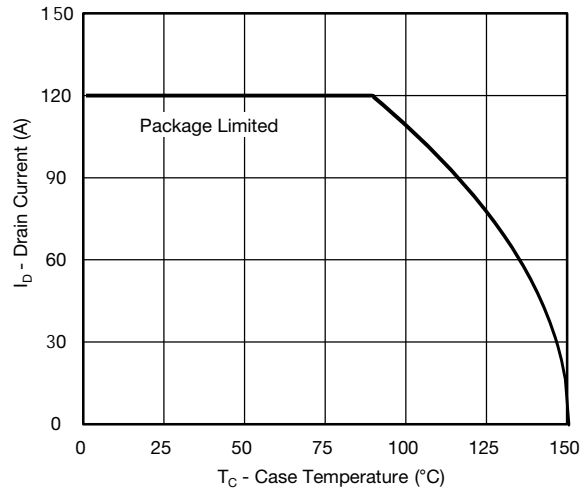
Single Pulse Power, Junction-to-Ambient



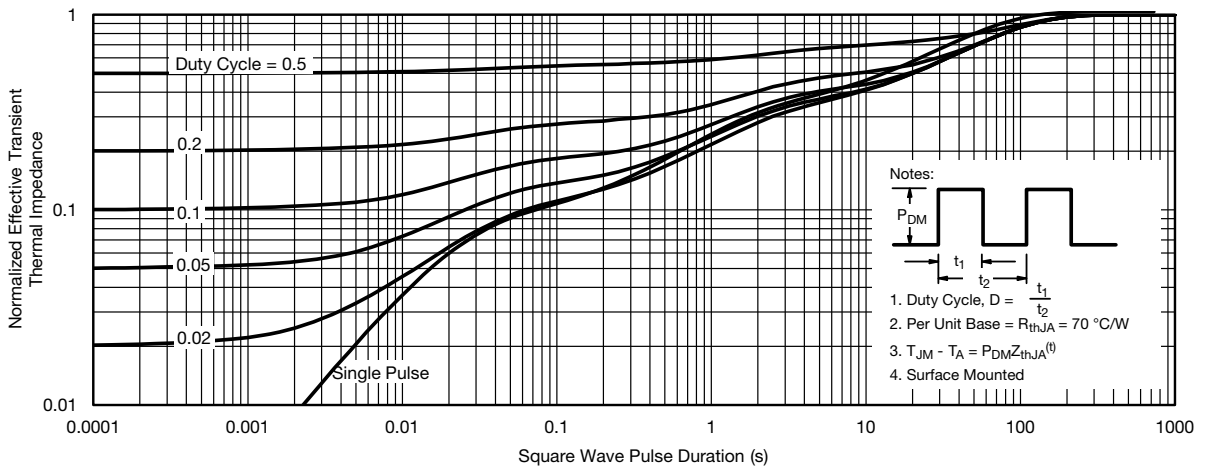
* $V_{GS} >$ minimum V_{GS} at which $R_{DS(on)}$ is specified

Safe Operating Area, Junction-to-Ambient

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

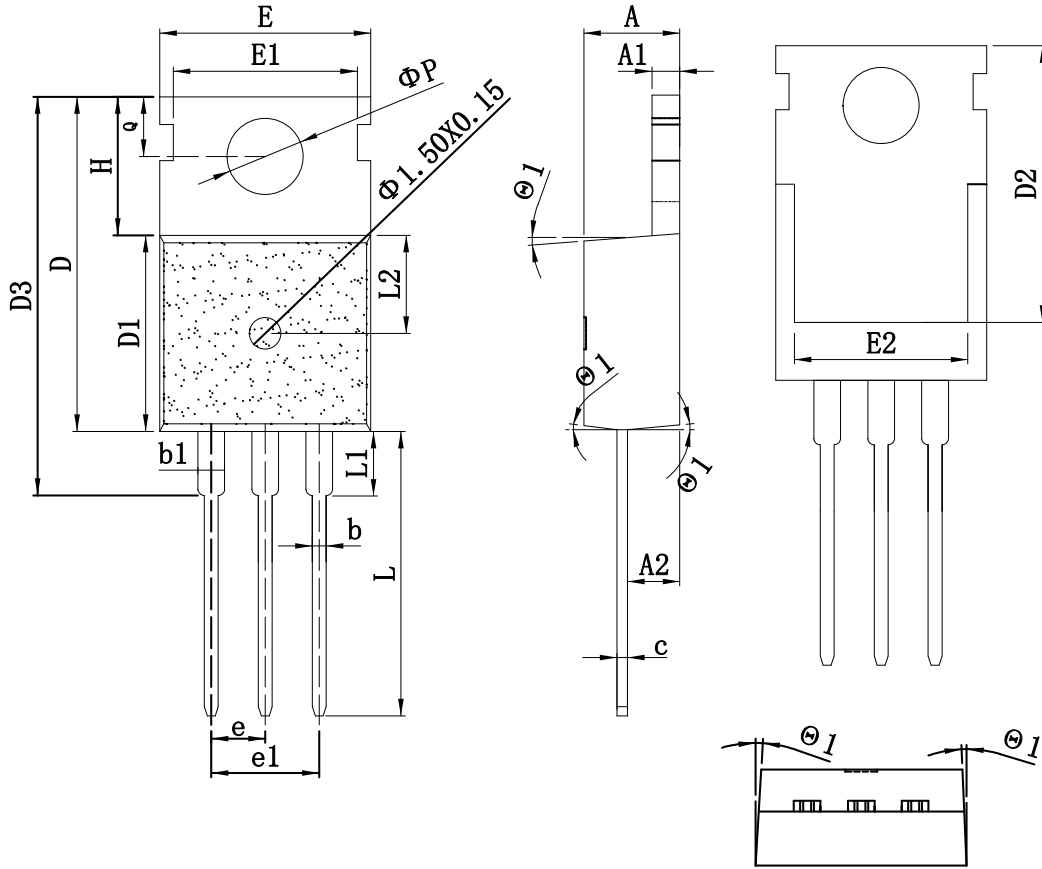


Current Derating*



Normalized Thermal Transient Impedance, Junction-to-Ambient

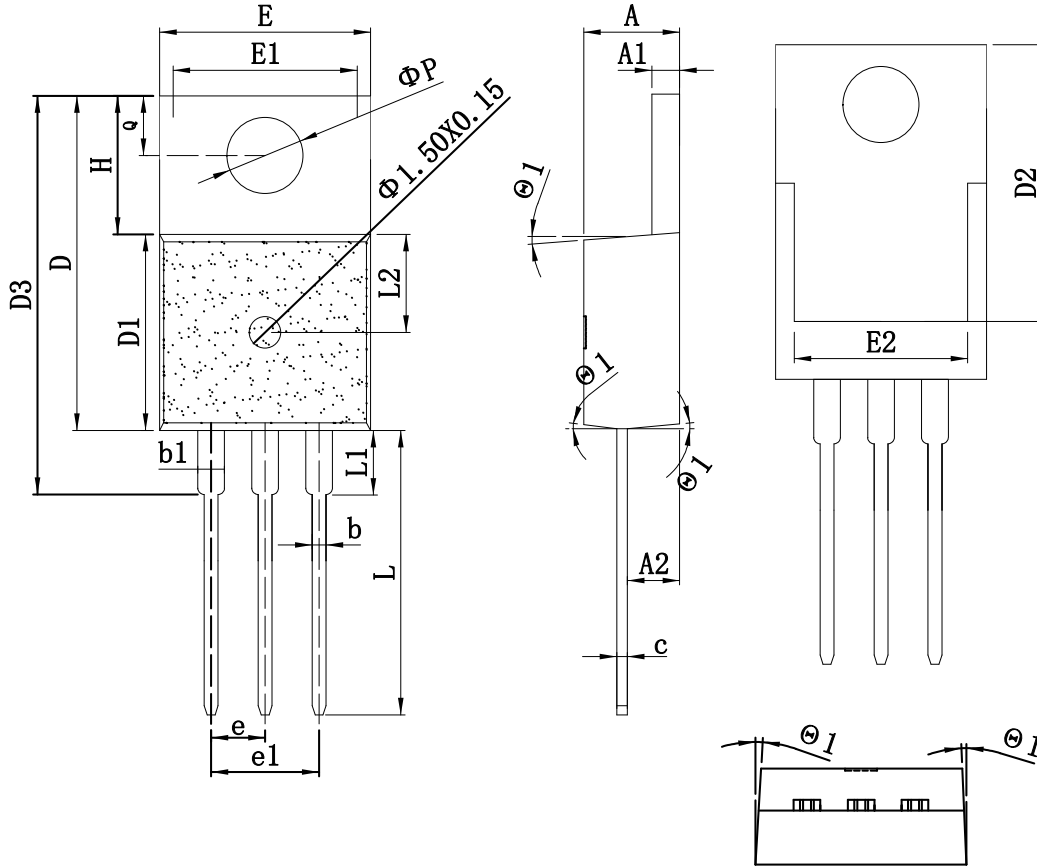
TO-220_3L-A PACKAGE OUTLINE



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	mm			SYMBOL	mm		
	MIN	TYP	MAX		MIN	TYP	MAX
A	4.15	4.50	4.80	E1	8.25	8.70	9.15
A1	1.15	1.30	1.50	E2	7.20	8.00	8.80
A2	2.10	2.40	2.65	e	2.38	2.54	2.74
b	0.65	0.80	1.00	e1	5.08REF		
b1	1.10	1.33	1.80	H	6.20	6.50	6.90
c	0.35	0.50	0.65	L	12.75	13.28	13.70
D	14.25	15.75	16.15	L1	-	-	3.50
D1	8.70	9.20	9.60	L2	2.30	4.65	7.00
D2	12.30	13.10	13.85	ϕP	3.40	3.65	3.85
D3	16.20	18.80	20.60	Q	2.50	2.80	3.00
E	8.68	10.02	11.00	θ	2°	-	7°

TO-220_3L-B PACKAGE OUTLINE



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	mm			SYMBOL	mm		
	MIN	TYP	MAX		MIN	TYP	MAX
A	4.15	4.50	4.80	E1	8.25	8.70	9.15
A1	1.15	1.30	1.50	E2	7.20	8.00	8.80
A2	2.10	2.40	2.65	e	2.38	2.54	2.74
b	0.65	0.80	1.00	e1	5.08REF		
b1	1.10	1.33	1.80	H	6.20	6.50	6.90
c	0.35	0.50	0.65	L	12.75	13.28	13.70
D	14.25	15.75	16.15	L1	-	-	3.50
D1	8.70	9.20	9.60	L2	2.30	4.65	7.00
D2	12.30	13.10	13.85	ϕP	3.40	3.65	3.85
D3	16.20	18.80	20.60	Q	2.50	2.80	3.00
E	8.68	10.02	11.00	θ	2°	-	7°

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